

# MUN2111T1 Series

Preferred Devices

## Bias Resistor Transistors

### PNP Silicon Surface Mount Transistors with Monolithic Bias Resistor Network

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SC-59 package which is designed for low power surface mount applications.

#### Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- Moisture Sensitivity Level: 1
- ESD Rating – Human Body Model: Class 1  
– Machine Model: Class B
- The SC-59 Package Can be Soldered Using Wave or Reflow
- The Modified Gull-Winged Leads Absorb Thermal Stress During Soldering Eliminating the Possibility of Damage to the Die
- Pb-Free Packages are Available

#### MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector – Base Voltage	$V_{CBO}$	50	Vdc
Collector – Emitter Voltage	$V_{CEO}$	50	Vdc
Collector Current	$I_C$	100	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	230 (Note 1) 338 (Note 2) 1.8 (Note 1) 2.7 (Note 2)	mW $^\circ\text{C/W}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	540 (Note 1) 370 (Note 2)	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Lead	$R_{\theta JL}$	264 (Note 1) 287 (Note 2)	$^\circ\text{C/W}$
Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

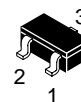
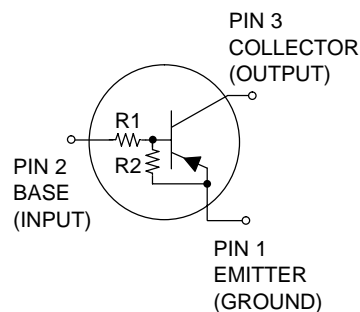
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-4 @ Minimum Pad.
2. FR-4 @ 1.0 x 1.0 inch Pad.



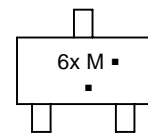
ON Semiconductor®

<http://onsemi.com>



SC-59  
CASE 318D  
PLASTIC

#### MARKING DIAGRAM



- 6x = Specific Device Code
- M = Date Code\*
- = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

#### ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

#### DEVICE MARKING INFORMATION

See device marking table on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

## MUN2111T1 Series

### DEVICE MARKING AND RESISTOR VALUES

Device	Package	Marking	R1 (K)	R2 (K)	Shipping†
MUN2111T1	SC-59	6A	10	10	3000 / Tape & Reel
MUN2111T1G	SC-59 (Pb-Free)	6A	10	10	
MUN2111T3G	SC-59 (Pb-Free)	6A	10	10	10,000 / Tape & Reel
MUN2112T1	SC-59	6B	22	22	3000 / Tape & Reel
MUN2112T1G	SC-59 (Pb-Free)	6B	22	22	
MUN2113T1	SC-59	6C	47	47	
MUN2113T1G	SC-59 (Pb-Free)	6C	47	47	
MUN2114T1	SC-59	6D	10	47	
MUN2114T1G	SC-59 (Pb-Free)	6D	10	47	
MUN2115T1 (Note 3)	SC-59	6E	10	∞	
MUN2115T1G (Note 3)	SC-59 (Pb-Free)	6E	10	∞	
MUN2116T1 (Note 3)	SC-59	6F	4.7	∞	
MUN2116T1G (Note 3)	SC-59 (Pb-Free)	6F	4.7	∞	
MUN2130T1 (Note 3)	SC-59	6G	1.0	1.0	
MUN2130T1G (Note 3)	SC-59 (Pb-Free)	6G	1.0	1.0	
MUN2131T1 (Note 3)	SC-59	6H	2.2	2.2	
MUN2131T1G (Note 3)	SC-59 (Pb-Free)	6H	2.2	2.2	
MUN2132T1 (Note 3)	SC-59	6J	4.7	4.7	
MUN2132T1G (Note 3)	SC-59 (Pb-Free)	6J	4.7	4.7	
MUN2133T1 (Note 3)	SC-59	6K	4.7	47	
MUN2133T1G (Note 3)	SC-59 (Pb-Free)	6K	4.7	47	
MUN2134T1 (Note 3)	SC-59	6L	22	47	
MUN2134T1G (Note 3)	SC-59 (Pb-Free)	6L	22	47	
MUN2136T1	SC-59	6N	100	100	
MUN2136T1G	SC-59 (Pb-Free)	6N	100	100	
MUN2137T1	SC-59	6P	47	22	
MUN2137T1G	SC-59 (Pb-Free)	6P	47	22	
MUN2140T1 (Note 3)	SC-59	6T	47	∞	
MUN2140T1G (Note 3)	SC-59 (Pb-Free)	6T	47	∞	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

3. New resistor combinations. Updated curves to follow in subsequent data sheets.

# MUN211T1 Series

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>					
Collector–Base Cutoff Current (V <sub>CB</sub> = 50 V, I <sub>E</sub> = 0)	I <sub>CBO</sub>	–	–	100	nAdc
Collector–Emitter Cutoff Current (V <sub>CE</sub> = 50 V, I <sub>B</sub> = 0)	I <sub>CEO</sub>	–	–	500	nAdc
Emitter–Base Cutoff Current (V <sub>EB</sub> = 6.0 V, I <sub>C</sub> = 0)	I <sub>EBO</sub>	–	–	0.5	mAdc
	MUN2111T1	–	–	0.2	
	MUN2112T1	–	–	0.1	
	MUN2113T1	–	–	0.2	
	MUN2114T1	–	–	0.9	
	MUN2115T1	–	–	1.9	
	MUN2116T1	–	–	4.3	
	MUN2130T1	–	–	2.3	
	MUN2131T1	–	–	1.5	
	MUN2132T1	–	–	0.18	
	MUN2133T1	–	–	0.13	
	MUN2134T1	–	–	0.05	
	MUN2136T1	–	–	0.13	
	MUN2137T1	–	–	0.20	
	MUN2140T1	–	–	–	
Collector–Base Breakdown Voltage (I <sub>C</sub> = 10 μA, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	50	–	–	Vdc
Collector–Emitter Breakdown Voltage (Note 4) (I <sub>C</sub> = 2.0 mA, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	50	–	–	Vdc
<b>ON CHARACTERISTICS (Note 4)</b>					
DC Current Gain (V <sub>CE</sub> = 10 V, I <sub>C</sub> = 5.0 mA)	h <sub>FE</sub>	35	60	–	
	MUN2111T1	60	100	–	
	MUN2112T1	80	140	–	
	MUN2113T1	80	140	–	
	MUN2114T1	160	250	–	
	MUN2115T1	160	250	–	
	MUN2116T1	3.0	5.0	–	
	MUN2130T1	8.0	15	–	
	MUN2131T1	15	27	–	
	MUN2132T1	80	140	–	
	MUN2133T1	80	130	–	
	MUN2134T1	80	150	–	
	MUN2136T1	80	140	–	
	MUN2137T1	80	140	–	
	MUN2140T1	120	250	–	
Collector–Emitter Saturation Voltage (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.3 mA)	V <sub>CE(sat)</sub>	–	–	0.25	Vdc
	MUN2111T1	–	–	0.25	
	MUN2112T1	–	–	0.25	
	MUN2113T1	–	–	0.25	
	MUN2114T1	–	–	0.25	
	MUN2115T1	–	–	0.25	
	MUN2130T1	–	–	0.25	
	MUN2133T1	–	–	0.25	
	MUN2136T1	–	–	0.25	
	MUN2137T1	–	–	0.25	
(I <sub>C</sub> = 10 mA, I <sub>B</sub> = 5.0 mA)	MUN2131T1	–	–	0.25	
(I <sub>C</sub> = 10 mA, I <sub>B</sub> = 1.0 mA)	MUN2116T1	–	–	0.25	
	MUN2132T1	–	–	0.25	
	MUN2134T1	–	–	0.25	
	MUN2140T1	–	–	0.25	
Output Voltage (on) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 2.5 V, R <sub>L</sub> = 1.0 kΩ)	V <sub>OL</sub>	–	–	0.2	Vdc
	MUN2111T1	–	–	0.2	
	MUN2112T1	–	–	0.2	
	MUN2114T1	–	–	0.2	
	MUN2115T1	–	–	0.2	
	MUN2116T1	–	–	0.2	
	MUN2130T1	–	–	0.2	
	MUN2131T1	–	–	0.2	
	MUN2132T1	–	–	0.2	
	MUN2133T1	–	–	0.2	
	MUN2134T1	–	–	0.2	
(V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 3.5 V, R <sub>L</sub> = 1.0 kΩ)	MUN2113T1	–	–	0.2	
	MUN2140T1	–	–	0.2	
(V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 5.5 V, R <sub>L</sub> = 1.0 kΩ)	MUN2136T1	–	–	0.2	
(V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 4.0 V, R <sub>L</sub> = 1.0 kΩ)	MUN2137T1	–	–	0.2	

4. Pulse Test: Pulse Width < 300 μs, Duty Cycle < 2.0%.

# MUN211T1 Series

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit	
<b>ON CHARACTERISTICS</b> (Note 4)						
Output Voltage (off) ( $V_{CC} = 5.0\text{ V}$ , $V_B = 0.5\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ )  ( $V_{CC} = 5.0\text{ V}$ , $V_B = 0.050\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ ) ( $V_{CC} = 5.0\text{ V}$ , $V_B = 0.25\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ )	MUN211T1 MUN212T1 MUN2113T1 MUN2114T1 MUN2133T1 MUN2134T1 MUN2136T1 MUN2137T1 MUN2130T1 MUN2115T1 MUN2116T1 MUN2131T1 MUN2132T1 MUN2140T1	$V_{OH}$	4.9 4.9 4.9 4.9 4.9 4.9 4.9 4.9 4.9 4.9 4.9 4.9 4.9 4.9	- - - - - - - - - - - - - -	- - - - - - - - - - - - - -	Vdc
Input Resistor	MUN211T1 MUN212T1 MUN2113T1 MUN2114T1 MUN2115T1 MUN2116T1 MUN2130T1 MUN2131T1 MUN2132T1 MUN2133T1 MUN2134T1 MUN2136T1 MUN2137T1 MUN2140T1	R1	7.0 15.4 32.9 7.0 7.0 3.3 0.7 1.5 3.3 3.3 15.4 70 32.9 32.9	10 22 47 10 10 4.7 1.0 2.2 4.7 4.7 22 100 47 47	13 28.6 61.1 13 13 6.1 1.3 2.9 6.1 6.1 28.6 130 61.1 61.1	k $\Omega$
Resistor Ratio	MUN211T1/MUN212T1/MUN2113T1/ MUN2136T1 MUN2114T1 MUN2115T1/MUN2116T1/MUN2140T1 MUN2130T1/MUN2131T1/MUN2132T1 MUN2133T1 MUN2134T1 MUN2137T1	$R_1/R_2$	0.8 0.17 - 0.8 0.055 0.38 1.7	1.0 0.21 - 1.0 0.1 0.47 2.1	1.2 0.25 - 1.2 0.185 0.56 2.6	

4. Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty Cycle < 2.0%.

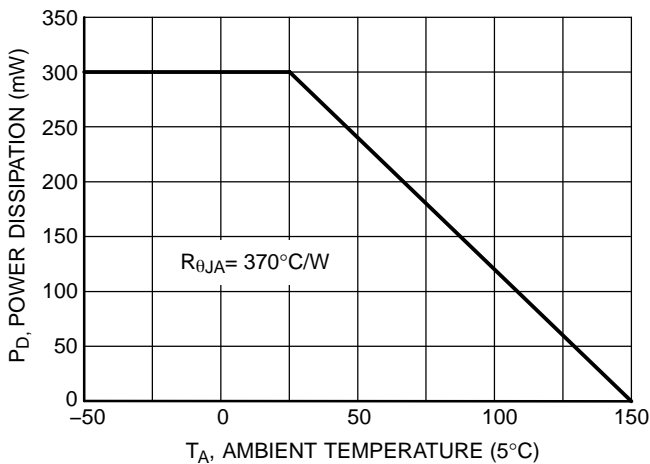


Figure 1. Derating Curve

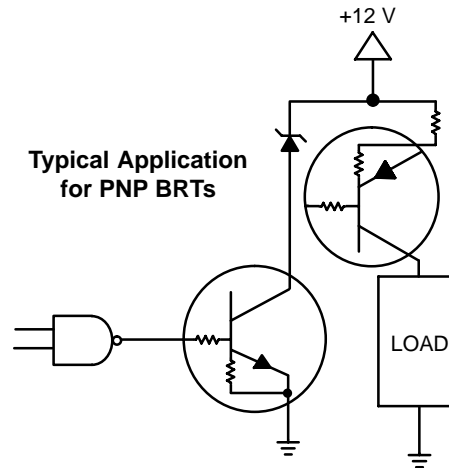


Figure 2. Inexpensive, Unregulated Current Source

# MUN211T1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS – MUN211T1

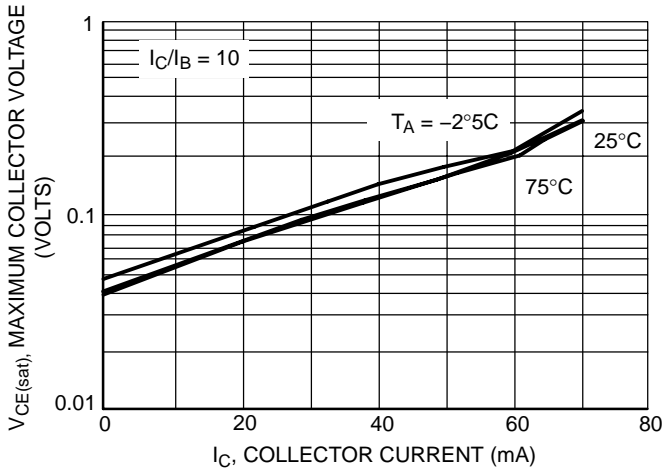


Figure 3.  $V_{CE(sat)}$  vs.  $I_C$

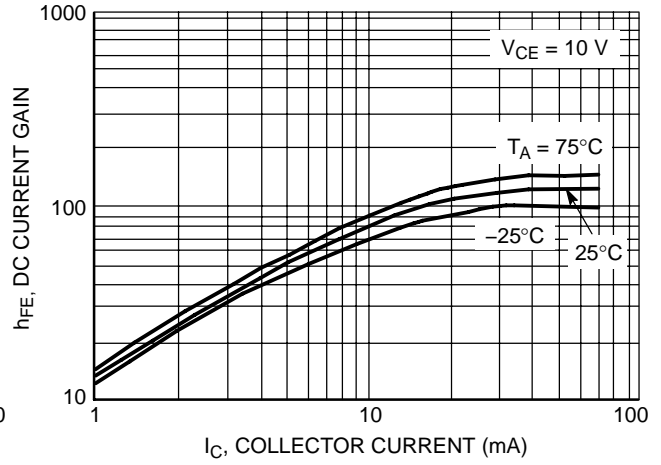


Figure 4. DC Current Gain

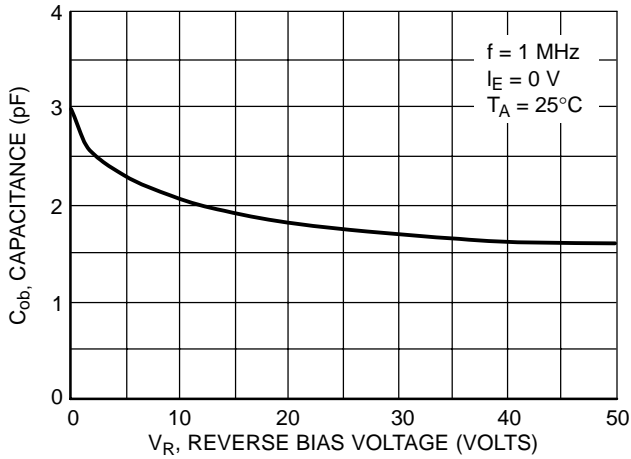


Figure 5. Output Capacitance

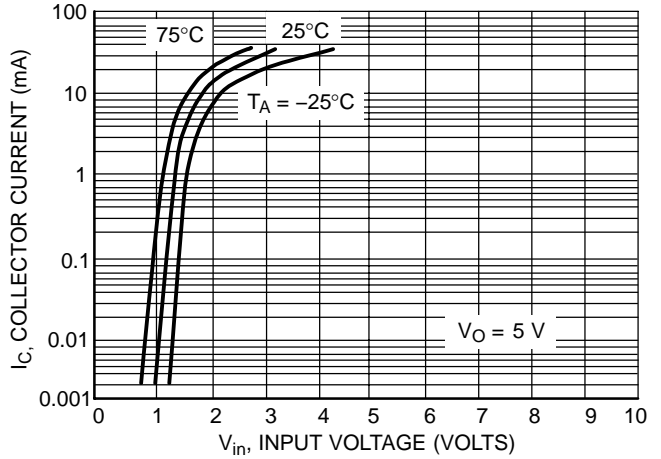


Figure 6. Output Current vs. Input Voltage

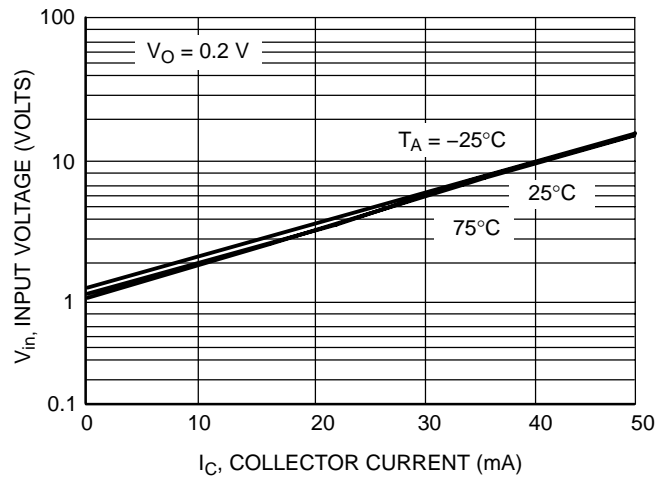


Figure 7. Input Voltage vs. Output Current

# MUN211T1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS – MUN2112T1

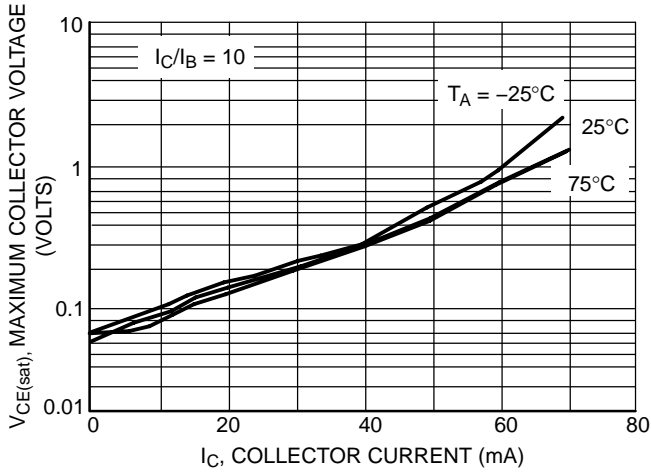


Figure 8.  $V_{CE(sat)}$  vs.  $I_C$

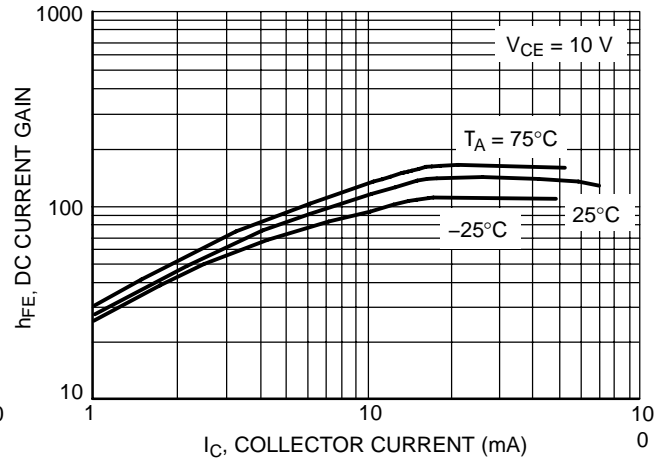


Figure 9. DC Current Gain

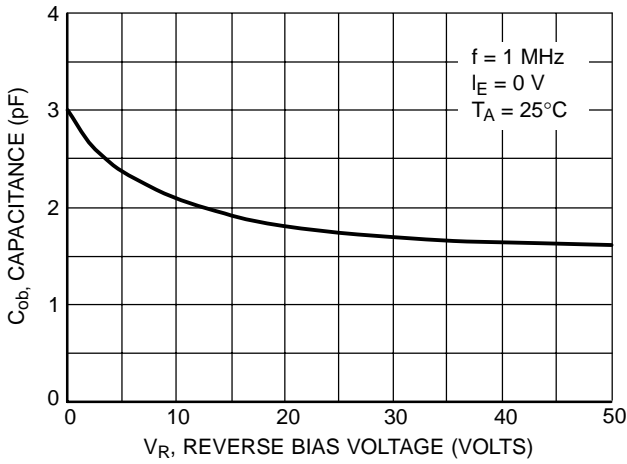


Figure 10. Output Capacitance

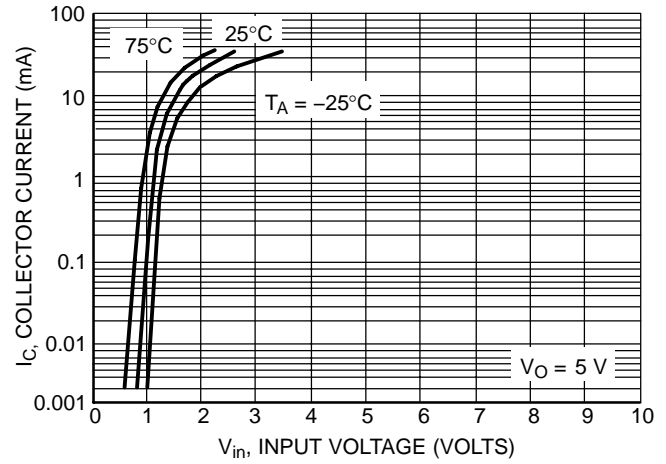


Figure 11. Output Current vs. Input Voltage

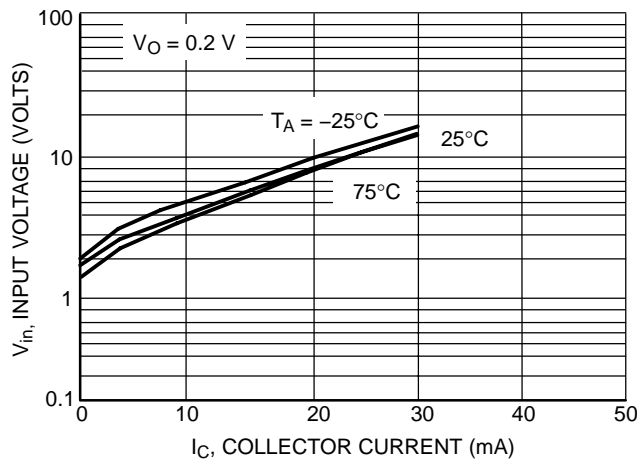


Figure 12. Input Voltage vs. Output Current

# MUN2111T1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS – MUN2113T1

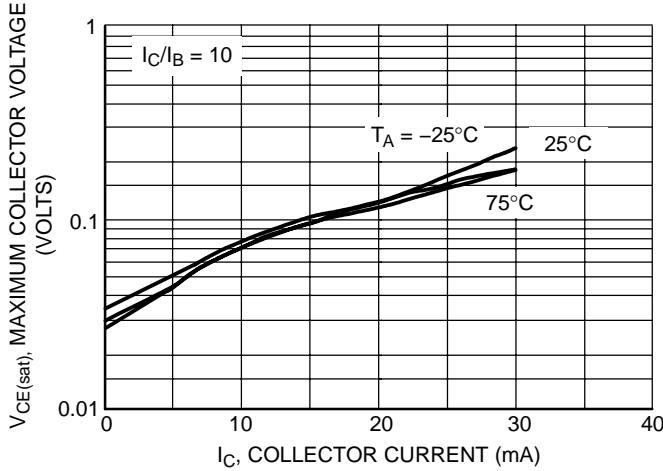


Figure 13.  $V_{CE(sat)}$  vs.  $I_C$

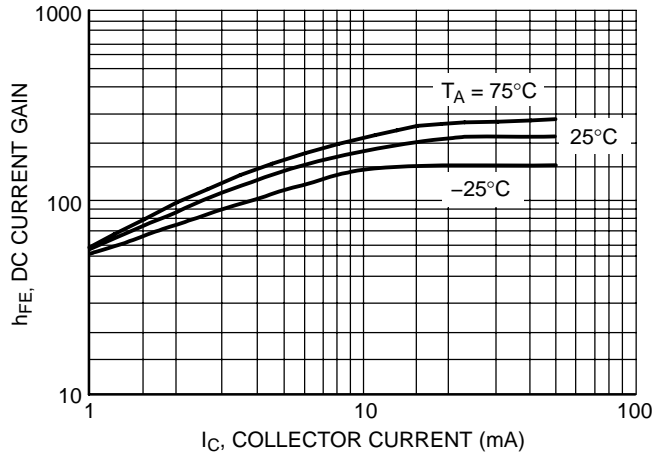


Figure 14. DC Current Gain

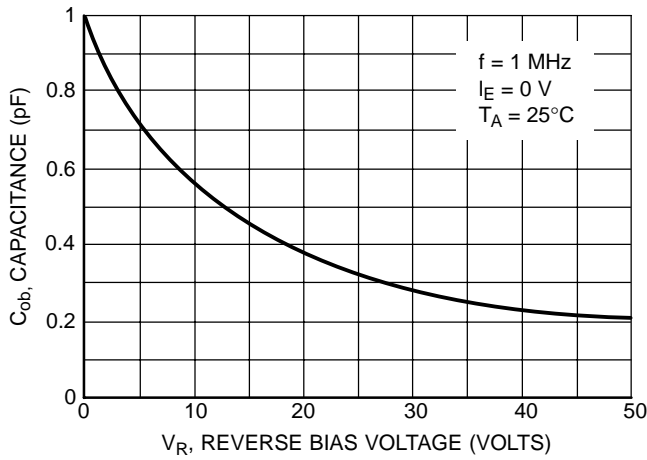


Figure 15. Output Capacitance

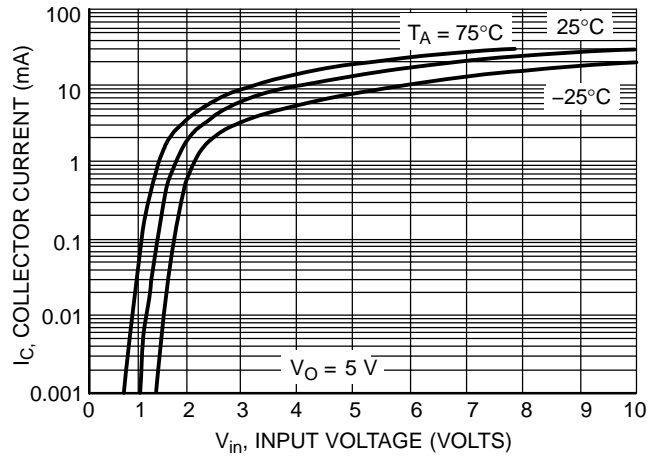


Figure 16. Output Current vs. Input Voltage

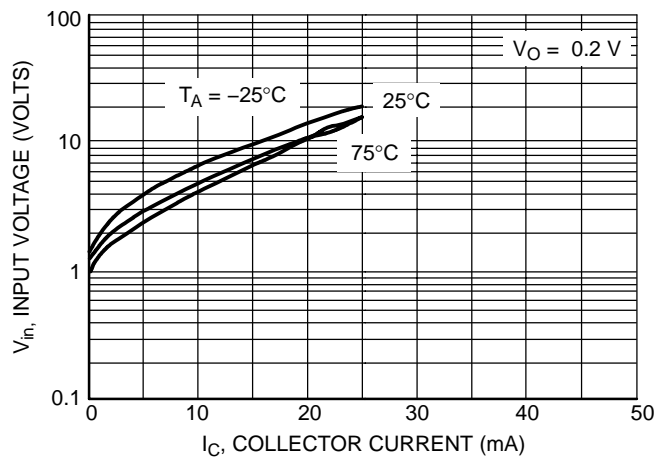


Figure 17. Input Voltage vs. Output Current

# MUN2111T1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS – MUN2114T1

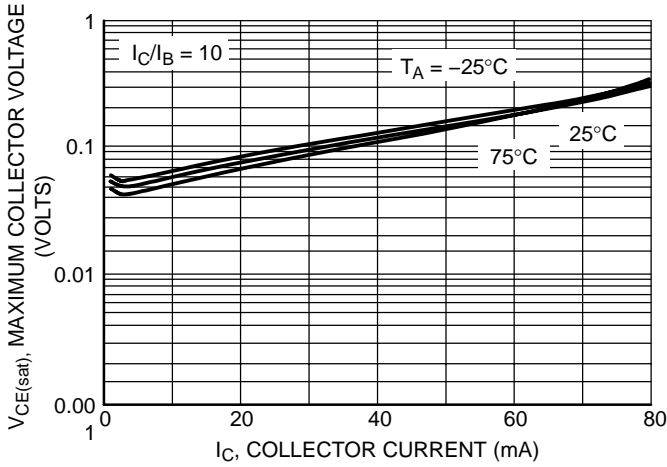


Figure 18.  $V_{CE(sat)}$  vs.  $I_C$

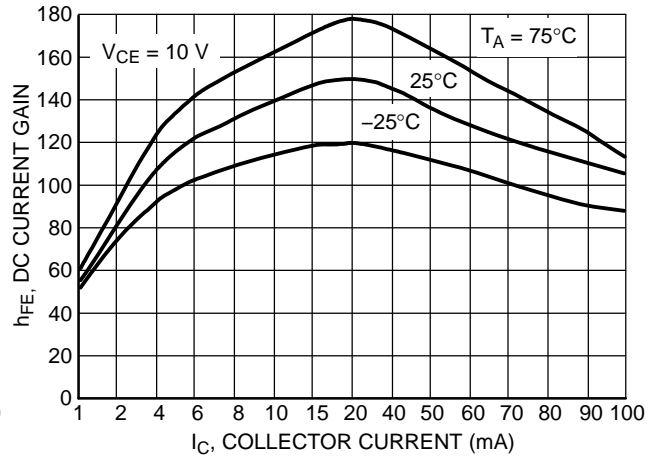


Figure 19. DC Current Gain

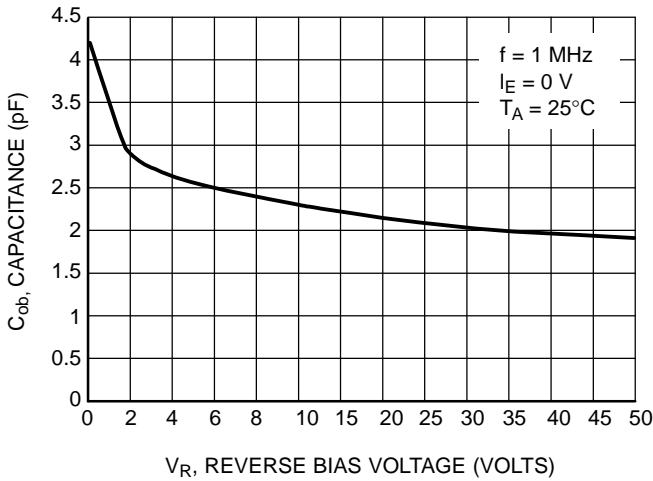


Figure 20. Output Capacitance

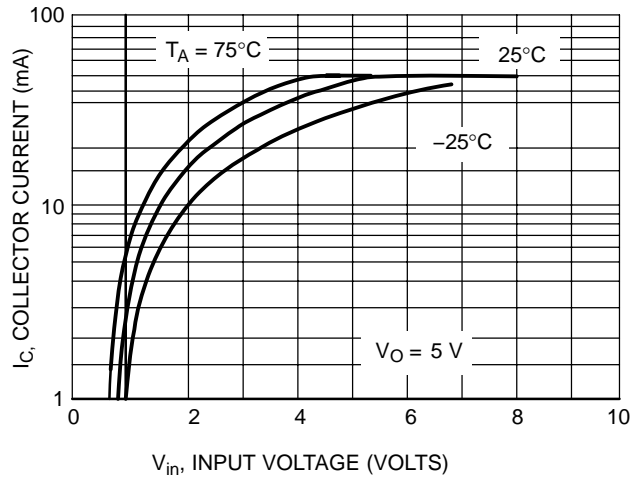


Figure 21. Output Current vs. Input Voltage

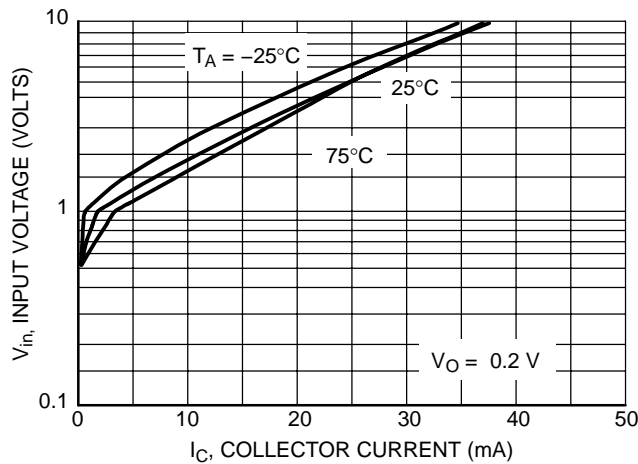


Figure 22. Input Voltage vs. Output Current



# MUN2111T1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS – MUN2131T1

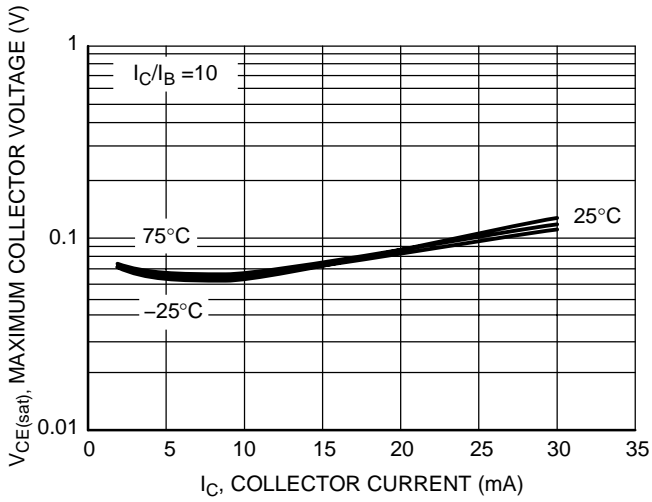


Figure 23.  $V_{CE(sat)}$  vs.  $I_C$

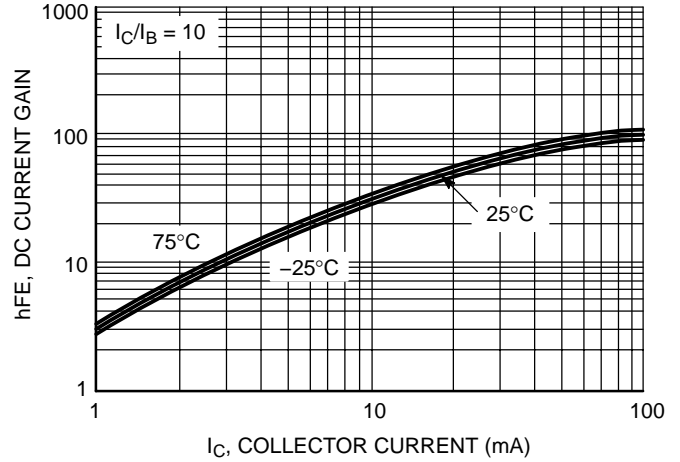


Figure 24. DC Current Gain

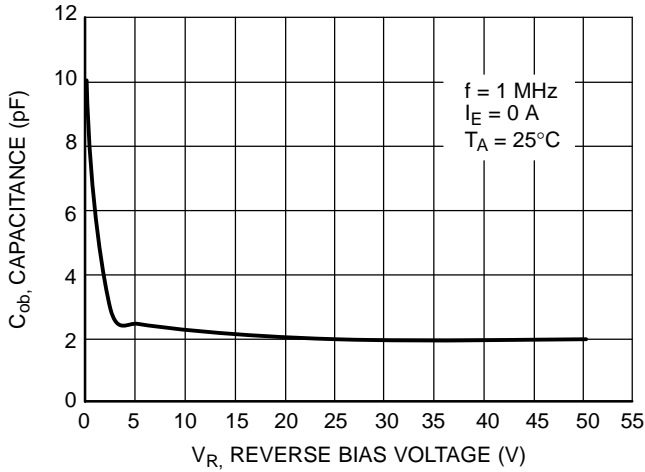


Figure 25. Output Capacitance

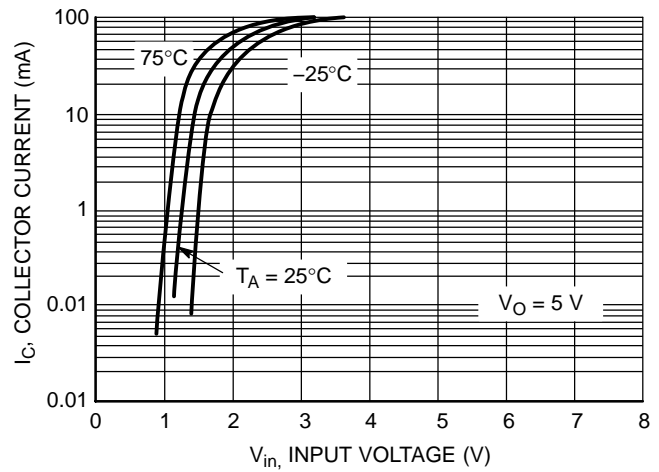


Figure 26. Output Current vs. Input Voltage

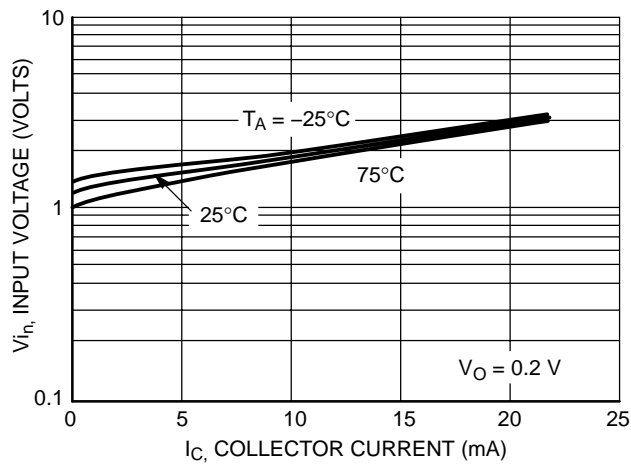


Figure 27. Input Voltage vs. Output Current

# MUN2111T1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS — MUN2133T1

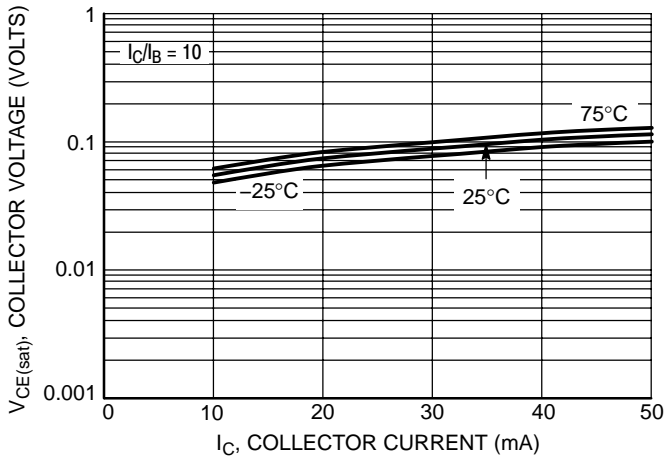


Figure 28.  $V_{CE(sat)}$  versus  $I_C$

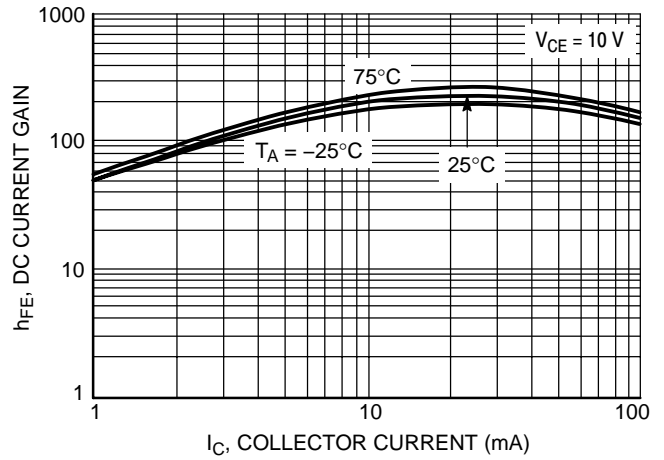


Figure 29. DC Current Gain

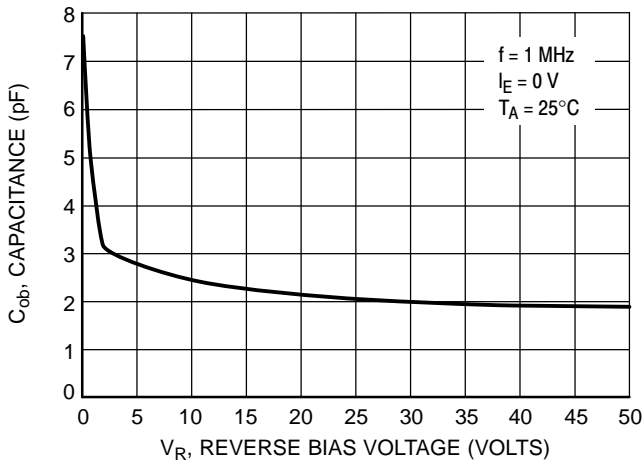


Figure 30. Output Capacitance

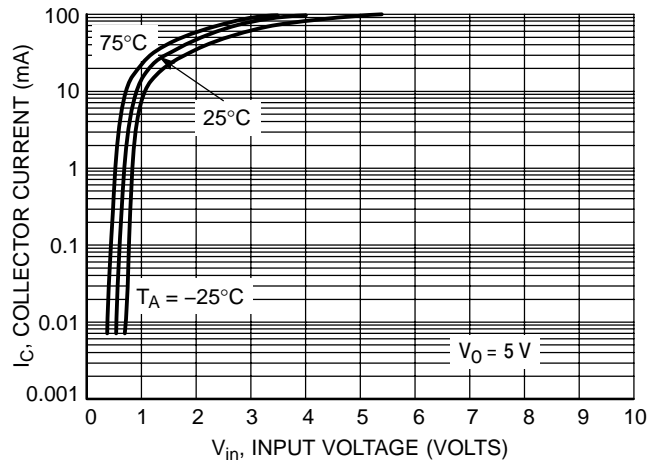


Figure 31. Output Current versus Input Voltage

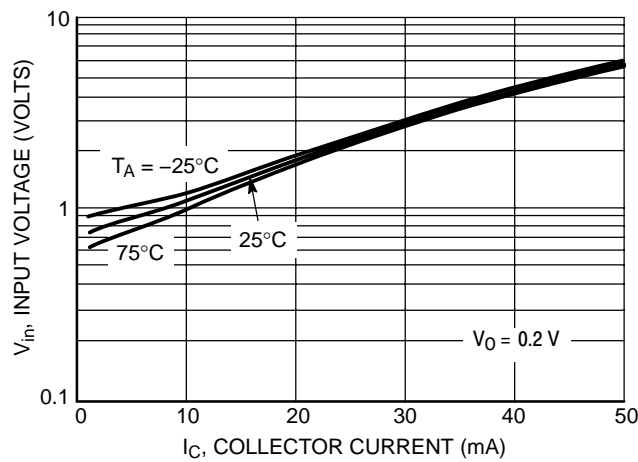
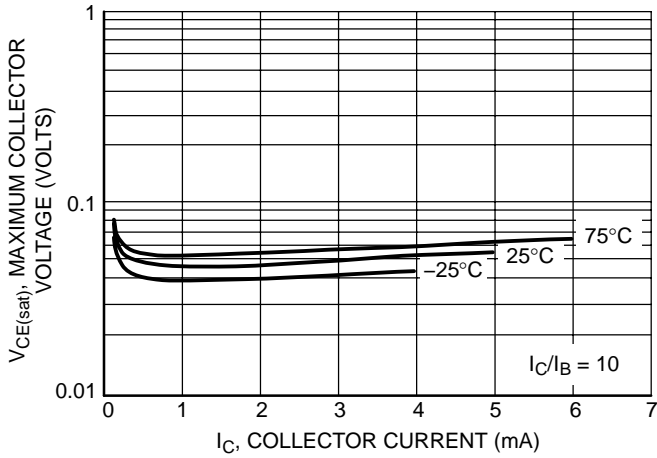


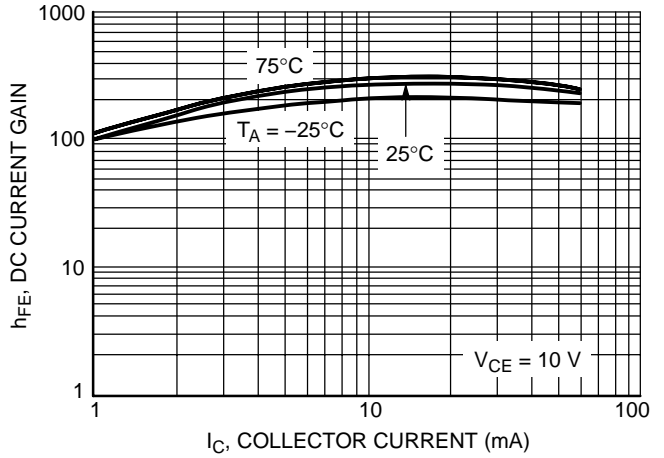
Figure 32. Input Voltage versus Output Current

# MUN2111T1 Series

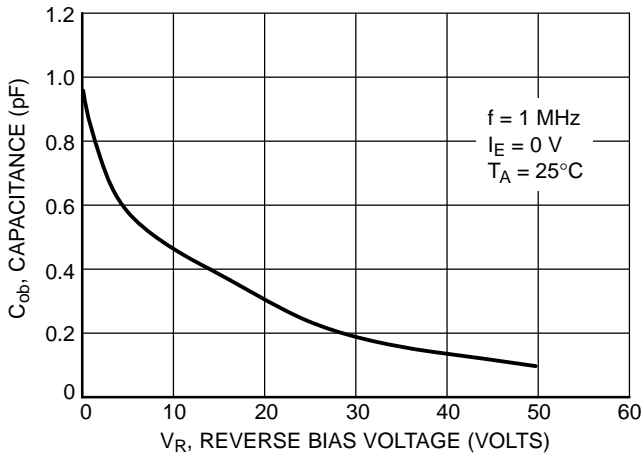
## TYPICAL ELECTRICAL CHARACTERISTICS — MUN2136T1



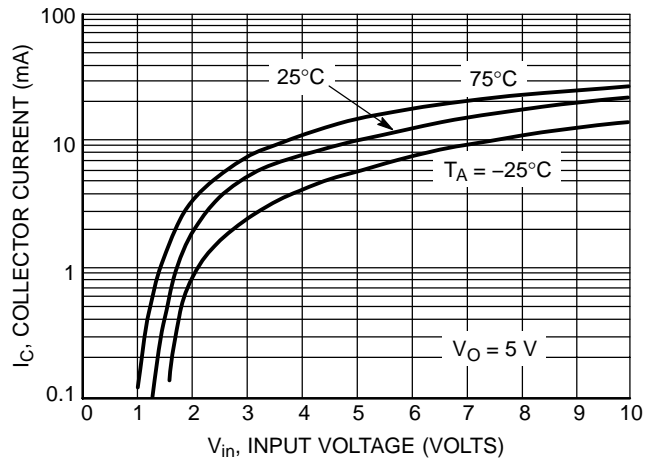
**Figure 33. Maximum Collector Voltage vs. Collector Current**



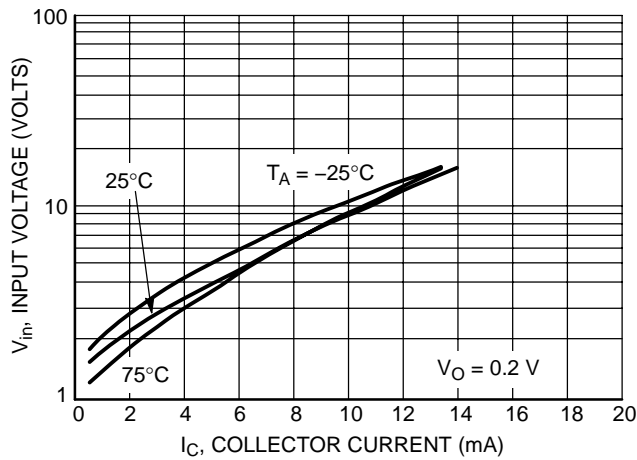
**Figure 34. DC Current Gain**



**Figure 35. Output Capacitance**



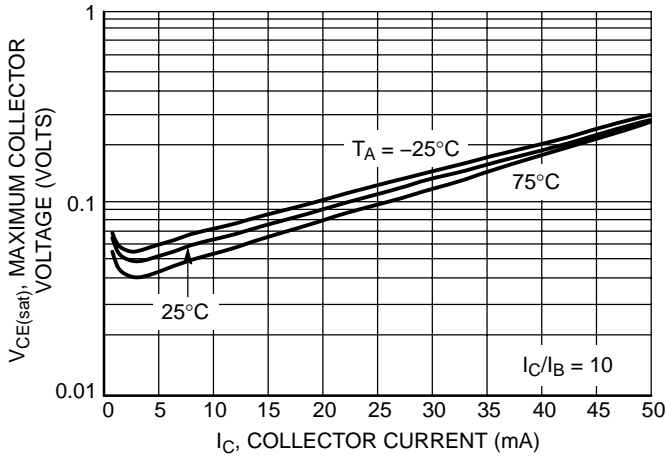
**Figure 36. Output Current vs. Input Voltage**



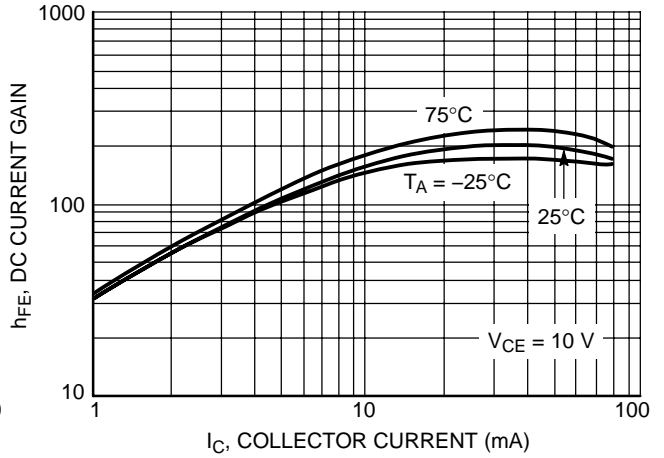
**Figure 37. Input Voltage vs. Output Current**

# MUN2111T1 Series

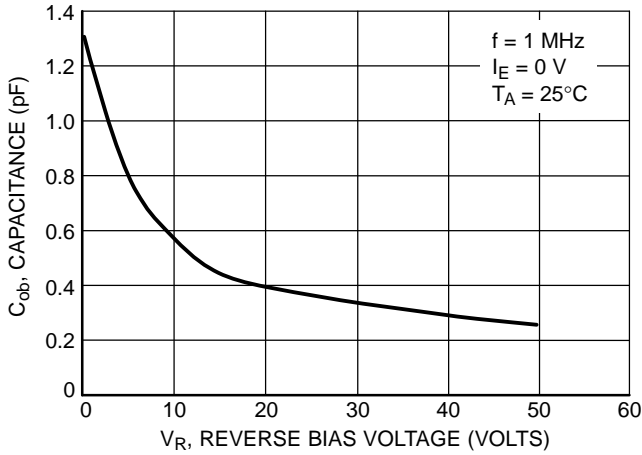
## TYPICAL ELECTRICAL CHARACTERISTICS — MUN2137T1



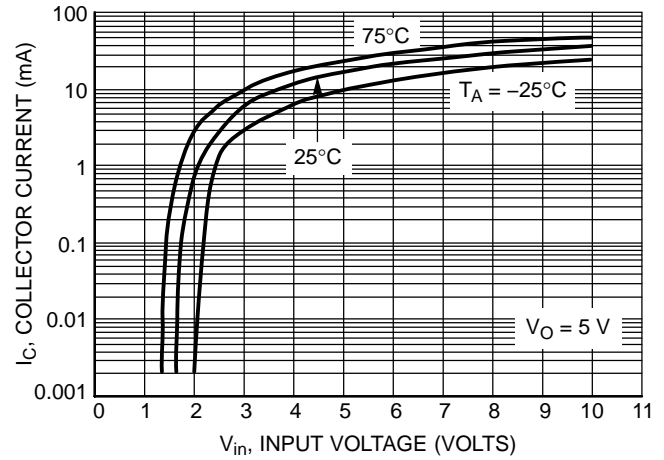
**Figure 38. Maximum Collector Voltage vs. Collector Current**



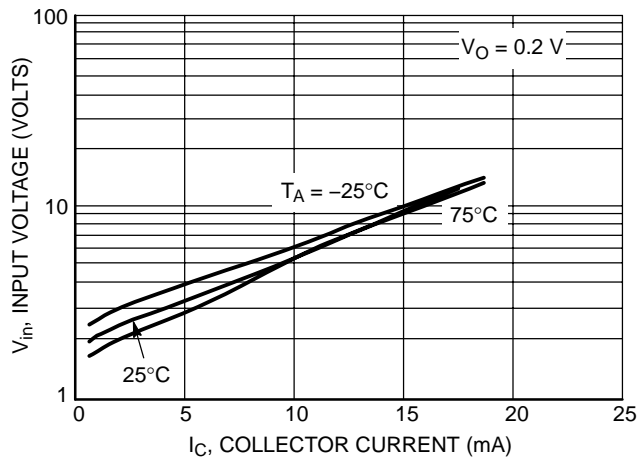
**Figure 39. DC Current Gain**



**Figure 40. Output Capacitance**



**Figure 41. Output Current vs. Input Voltage**

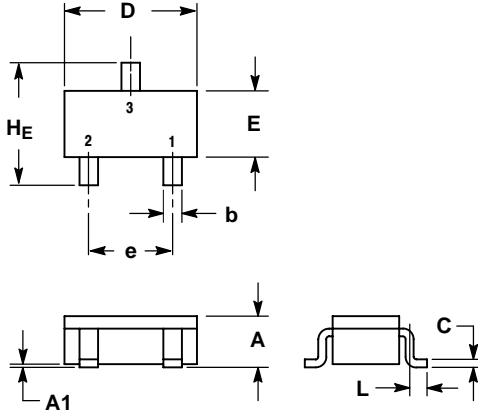


**Figure 42. Input Voltage vs. Output Current**

# MUN2111T1 Series

## PACKAGE DIMENSIONS

SC-59  
CASE 318D-04  
ISSUE G

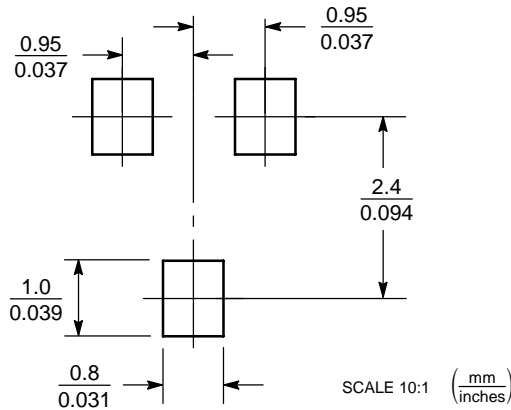


NOTES:  
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.00	1.15	1.30	0.039	0.045	0.051
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.35	0.43	0.50	0.014	0.017	0.020
c	0.09	0.14	0.18	0.003	0.005	0.007
D	2.70	2.90	3.10	0.106	0.114	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
e	1.70	1.90	2.10	0.067	0.075	0.083
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.80	3.00	0.099	0.110	0.118

STYLE 1:  
PIN 1. EMITTER  
2. BASE  
3. COLLECTOR

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
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